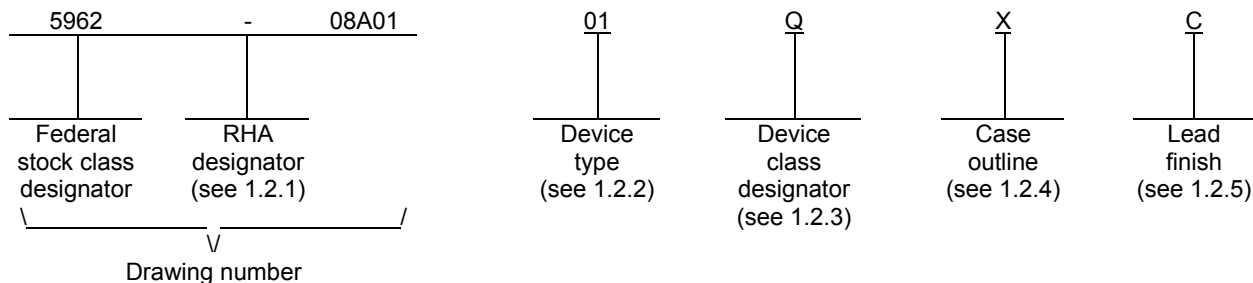


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				SHEET		1	2	3	4	5	6	7	8	9	10	11	12	13	
PMIC N/A				PREPARED BY Phu H. Nguyen						DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216 http://www.dscc.dla.mil									
STANDARD MICROCIRCUIT DRAWING THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE AMSC N/A				CHECKED BY Phu H. Nguyen															
				APPROVED BY Thomas M. Hess															
				DRAWING APPROVAL DATE 08-01-09															
								REVISION LEVEL						SIZE A		CAGE CODE 67268		5962-08A01	
								SHEET 1 OF 13											

1. SCOPE

1.1 Scope. This drawing documents two product assurance class levels consisting of high reliability (device classes Q and M) and space application (device class V). A choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). When available, a choice of Radiation Hardness Assurance (RHA) levels are reflected in the PIN.

1.2 PIN. The PIN is as shown in the following example:



1.2.1 RHA designator. Device classes Q and V RHA marked devices meet the MIL-PRF-38535 specified RHA levels and are marked with the appropriate RHA designator. Device class M RHA marked devices meet the MIL-PRF-38535, appendix A specified RHA levels and are marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.

1.2.2 Device type(s). The device type(s) identify the circuit function as follows:

<u>Device type</u>	<u>Generic number</u>	<u>Circuit function</u>
01	AT7911E	Triple SpaceWire links High Speed Controller

1.2.3 Device class designator. The device class designator is a single letter identifying the product assurance level as follows:

<u>Device class</u>	<u>Device requirements documentation</u>
M	Vendor self-certification to the requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535, appendix A
Q or V	Certification and qualification to MIL-PRF-38535

1.2.4 Case outline(s). The case outline(s) are as designated in MIL-STD-1835 and as follows:

<u>Outline letter</u>	<u>Descriptive designator</u>	<u>Terminals</u>	<u>Package style</u>
X	See figure 1	196	Multilayer Quad Flat Pack

1.2.5 Lead finish. The lead finish is as specified in MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.

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1.3 Absolute maximum ratings. 1/2/

Supply voltage range (V_{CC}).....-0.5 V to 7.0 V dc
Power dissipation (P_d).....1.7 W
Storage temperature range.....-65°C to 150°C
Maximum junction temperature (T_J).....175°C
Thermal resistance junction to case (θ_{jc})4°C/W

1.4 Recommended operating conditions.

Supply voltage range (V_{CC}).....4.5 V to 5.5 V dc or 3.0 V to 3.6 V dc
Ambient operating temperature (T_A) -55°C to 125°C

2. APPLICABLE DOCUMENTS

2.1 Government specification, standards, and handbooks. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 - Test Method Standard Microcircuits.
MIL-STD-1835 - Interface Standard Electronic Component Case Outlines.

DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings.
MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at <http://assist.daps.dla.mil/quicksearch/> or www.dodssp.daps.mil or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

- 1/ Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.
2/ All voltage referenced to ground unless otherwise specified

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3. REQUIREMENTS

3.1 Item requirements. The individual item requirements for device classes Q and V shall be in accordance with MIL-PRF-38535 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. The individual item requirements for device class M shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein for device classes Q and V or MIL-PRF-38535, appendix A and herein for device class M.

3.2.1 Case outline(s). The case outline(s) shall be in accordance with 1.2.4 herein and figure 1.

3.2.2 Terminal connections. The terminal connections shall be as specified on figure 2.

3.2.3 Block or logic diagram(s). The block or logic diagram(s) shall be as specified on figure 3.

3.2.4 Timing waveforms. The timing waveforms shall be as specified on figure 4.

3.2.5 Radiation exposure circuit. The radiation exposure circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing and acquiring activity upon request.

3.3 Electrical performance characteristics and postirradiation parameter limits. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full case operating temperature range.

3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are defined in table I.

3.5 Marking. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device. For RHA product using this option, the RHA designator shall still be marked. Marking for device classes Q and V shall be in accordance with MIL-PRF-38535. Marking for device class M shall be in accordance with MIL-PRF-38535, appendix A.

3.5.1 Certification/compliance mark. The certification mark for device classes Q and V shall be a "QML" or "Q" as required in MIL-PRF-38535. The compliance mark for device class M shall be a "C" as required in MIL-PRF-38535, appendix A.

3.6 Certificate of compliance. For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.6.1 herein). For device class M, a certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6.2 herein). The certificate of compliance submitted to DSCC-VA prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device classes Q and V, the requirements of MIL-PRF-38535 and herein or for device class M, the requirements of MIL-PRF-38535, appendix A and herein.

3.7 Certificate of conformance. A certificate of conformance as required for device classes Q and V in MIL-PRF-38535 or for device class M in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.

3.8 Notification of change for device class M. For device class M, notification to DSCC-VA of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change that affects this drawing.

3.9 Verification and review for device class M. For device class M, DSCC, DSCC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

3.10 Microcircuit group assignment for device class M. Device class M devices covered by this drawing shall be in microcircuit group number 123 (see MIL-PRF-38535, appendix A).

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TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C 4.5 V ≤ V_{CC} ≤ 5.5 V unless otherwise specified	Group A subgroups	Limits		Unit
				Min	Max	
Low level input voltage	V _{IL}		1,2,3		0.8	V
High level input voltage	V _{IH}		1,2,3	2.2		V
Low level input current	I _{IL}	V _{IN} = GND, V _{CC} = 5.5 V	1,2,3	-5		μA
Low level input current Pull-down	I _{ILPD}	V _{IN} = GND, V _{CC} = 5.5 V	1,2,3	-5		μA
Low level input current Pull-up	I _{ILPU}	V _{IN} = GND, V _{CC} = 5.5V	1,2,3	-120		μA
High level input current	I _{IH}	V _{IN} = V _{CC} = 5.5 V	1,2,3		5	μA
High level input current Pull-up	I _{IHPU}	V _{IN} = V _{CC} = 5.5 V	1,2,3		5	μA
High level input current Pull-down	I _{IHPD}	V _{IN} = V _{CC} = 5.5 V	1,2,3		330	μA
Output leakage low current	I _{OZL}	Outputs disabled V _{OUT} = GND	1,2,3	-5		μA
Output leakage low current Pull-down output	I _{OZLPD}	Outputs disabled, V _{OUT} = GND	1,2,3	-5		μA
Output leakage low current Pull-up output	I _{OZLPU}	Outputs disabled V _{OUT} = GND	1,2,3	-120		μA
Output leakage high current	I _{OZH}	Outputs disabled, V _{OUT} = V _{CC}	1,2,3		5	μA
Output leakage high current Pull-up output	I _{OZHPU}	Outputs disabled, V _{OUT} = V _{CC}	1,2,3		5	μA
Output leakage high current Pull-down output	I _{OZHPD}	Outputs disabled, V _{OUT} = V _{CC}	1,2,3		330	μA
Low level output voltage	V _{OL}	V _{CC} = 4.5 V I _{OL} = 3, 6, 12 mA	1,2,3		0.4	V
High level output voltage	V _{OH}	V _{CC} = 4.5 V I _{OH} = -3, -6, -12 mA	1,2,3	3.9		V
Output short circuit current	I _{OS}	V _{OUT} = V _{CC} V _{OUT} = GND	1,2,3		90 <u>1</u> / 180 <u>2</u> / 270 <u>3</u> /	mA
Supply current when not clocked	I _{CCSB}		1,2,3		8	mA
Supply current in RESET	I _{CCRES}		1,2,3		75	mA
Supply current in IDLE	I _{CCIDLE}		1,2,3		115	mA
Operating supply current	I _{CCOP}		1,2,3		310	mA
Input capacitance 4/	C _{IN}	V _{CC} = 0 V	4		15	pF
Input/Output capacitance 4/	C _{IO}	V _{CC} = 0 V	4		15	pF
CLK low to HACK high	t _{p1}		9,10,11		29	ns
CLK high to CMCS0* high	t _{p2}		9,10,11		18	ns
CLK high to CMADR0 high	t _{p3}		9,10,11		17	ns
CLK10 high to LDO1 high	t _{p4}		9,10,11		30	ns
CLK10 high to LDO2 high	t _{p5}		9,10,11		32	ns
CLK10 high to LDO3 high	t _{p6}		9,10,11		36	ns

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C 3.0 V ≤ V_{CC} ≤ 3.6 V unless otherwise specified	Group A subgroups	Limits		Unit
				Min	Max	
Low level input voltage	V _{IL}		1, 2, 3		0.8	V
High level input voltage	V _{IH}		1, 2, 3	2.0		V
Low level input current	I _{IL}	V _{IN} = GND, V _{CC} = 3.3 V	1, 2, 3	-1		μA
Low level input current Pull-down	I _{ILPD}	V _{IN} = GND, V _{CC} = 3.3 V	1, 2, 3	-1		μA
Low level input current Pull-up	I _{ILPU}	V _{IN} = GND, V _{CC} = 3.3 V	1, 2, 3	-60		μA
High level input current	I _{IH}	V _{IN} = V _{CC} = 3.3V	1, 2, 3		1	μA
High level input current Pull-up	I _{IHPU}	V _{IN} = V _{CC} = 3.3V	1, 2, 3		1	μA
High level input current Pull-down	I _{IHPD}	V _{IN} = V _{CC} = 3.3V	1, 2, 3		150	μA
Output leakage low current	I _{OZL}	Outputs disabled, V _{OUT} = GND	1, 2, 3	-1		μA
Output leakage low current Pull-down output	I _{OZLPD}	Outputs disabled, V _{OUT} = GND	1, 2, 3	-1		μA
Output leakage low current Pull-up output	I _{OZLPU}	Outputs disabled, V _{OUT} = GND	1, 2, 3	-60		μA
Output leakage high current	I _{OZH}	Outputs disabled, V _{OUT} = V _{CC}	1, 2, 3		1	μA
Output leakage high current Pull-up output	I _{OZHPU}	Outputs disabled, V _{OUT} = V _{CC}	1, 2, 3		1	μA
Output leakage high current Pull-down output	I _{OZHPD}	Outputs disabled, V _{OUT} = V _{CC}	1, 2, 3		150	μA
Low level output voltage	V _{OL}	V _{CC} = 3.0V I _{OL} = 1, 2, 4 mA	1, 2, 3		0.4	V
high level output voltage	V _{OH}	V _{CC} = 3.0V I _{OH} = 1.5, 3, 6 mA	1, 2, 3	2.4		V
Output short circuit current	I _{OS}	V _{OUT} = V _{CC} V _{OUT} = GND	1, 2, 3		50 <u>1/</u> 100 <u>2/</u> 155 <u>3/</u>	mA
Supply current when not clocked	I _{CCSB}		1, 2, 3		4	mA
Supply current in RESET	I _{CCRES}		1, 2, 3		24	mA
Supply current in IDLE	I _{CCIDLE}		1, 2, 3		38	mA
Operating supply current	I _{CCOP}		1, 2, 3		100	mA
Input capacitance 4/	C _{IN}	V _{CC} = 0 V	4		15	pF
Input/Output capacitance 4/	C _{IO}	V _{CC} = 0 V	4		15	pF
CLK low to HACK high	t _{p1}		9, 10, 11		47	ns
CLK high to CMCS0* high	t _{p2}		9, 10, 11		30	ns
CLK high to CMADR0 high	t _{p3}		9, 10, 11		28	ns
CLK10 high to LDO1 high	t _{p4}		9, 10, 11		51	ns
CLK10 high to LDO2 high	t _{p5}		9, 10, 11		54	ns
CLK10 high to LDO3 high	t _{p6}		9, 10, 11		61	ns

1/ Applicable for HDATA[31:0], HACK, HINTR*, CMDATA[31:0], COCI, CPUR*, SES[3:0]* and TDO pins.

2/ Applicable for CMCS[1:0]*, CMRD*, CMWR* and CMADR[31:0] pins.

3/ Applicable for LDO1, LSO1, LDO2, LSO2, LDO3 and LSO3 pins.

4/ This parameter is tested initially and after major process changes, otherwise guaranteed.

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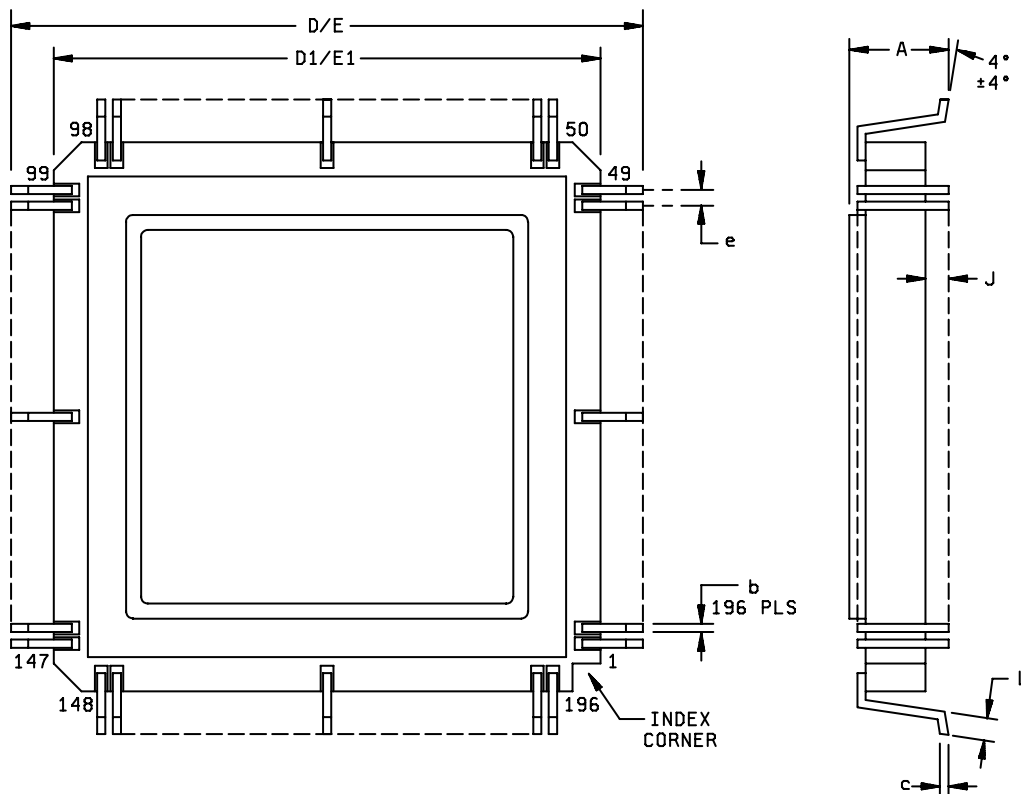
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	Millimeters		Inches	
A	2.36	2.97	.093	.117
C	0.20 Typ		.008 Typ	
D/E	38.74	39.75	1.525	1.565
D1/E1	34.03	34.54	1.340	1.360
e	0.635 BSC		.025 BSC	
J	0.15	0.30	.006	.012
L	0.61	1.01	.024	.040

NOTE:

Lid is connected to ground.

FIGURE 1. Case outline.

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Pin Number	Name	Pin Number	Name	Pin Number	Name	Pin Number	Name	Pin Number	Name
1	PLLOUT	41	VCC	81	HDATA28	121	CMDATA0	161	GND
2	GND	42	GND	82	HDATA29	122	CMDATA1	162	CMDATA27
3	VCC	43	HDATA0	83	VCC	123	CMDATA2	163	CMDATA28
4	CLK	44	HDATA1	84	GND	124	VCC	164	CMDATA29
5	RESET*	45	HDATA2	85	HDATA30	125	GND	165	CMDATA30
6	CLK10	46	HDATA3	86	HDATA31	126	CMDATA3	166	CMDATA31
7	HOSTBIGE	47	HDATA4	87	CPUR*	127	CMDATA4	167	GND
8	TCK	48	HDATA5	88	SES0*	128	CMDATA5	168	GND
9	TMS	49	HDATA6	89	SES1*	129	VCC	169	VCC_3VOLT
10	TDI	50	VCC	90	SES2*	130	GND	170	GND
11	TRST*	51	GND	91	SES3*	131	CMDATA6	171	GND
12	TDO	52	HDATA7	92	CAM	132	CMDATA7	172	VCC
13	VCC	53	HDATA8	93	COCI	133	CMDATA8	173	GND
14	GND	54	HDATA9	94	COCO	134	VCC	174	GND
15	HSEL*	55	HDATA10	95	CMCS0*	135	GND	175	NC
16	HRD*	56	HDATA11	96	CMCS1*	136	CMDATA9	176	LDI1
17	HWR*	57	VCC	97	VCC	137	CMDATA10	177	LSI1
18	HACK	58	GND	98	GND	138	CMDATA11	178	LDO1
19	HINTR*	59	HDATA12	99	CMRD*	139	CMDATA12	179	LSO1
20	VCC	60	HDATA13	100	CMWR*	140	CMDATA13	180	LDI2
21	GND	61	HDATA14	101	CMADR0	141	CMDATA14	181	LSI2
22	HADR0	62	HDATA15	102	CMADR1	142	VCC	182	NC
23	HADR1	63	HDATA16	103	CMADR2	143	GND	183	VCC
24	HADR2	64	HDATA17	104	CMADR3	144	CMDATA15	184	VCC
25	HADR3	65	VCC	105	CMADR4	145	CMDATA16	185	VCC
26	HADR4	66	GND	106	VCC	146	CMDATA17	186	LDO2
27	HADR5	67	HDATA18	107	GND	147	CMDATA18	187	LSO2
28	HADR6	68	HDATA19	108	CMADR5	148	CMDATA19	188	LDI3
29	HADR7	69	HDATA20	109	CMADR6	149	CMDATA20	189	LSI3
30	VCC	70	HDATA21	110	CMADR7	150	VCC	190	LDO3
31	GND	71	HDATA22	111	CMADR8	151	GND	191	LSO3
32	BOOTLINK	72	HDATA23	112	CMADR9	152	CMDATA21	192	TIME_CODE_SYNC
33	SCMSADR0	73	VCC	113	CMADR10	153	CMDATA22	193	GND
34	SMCSADR1	74	GND	114	CMADR11	154	CMDATA23	194	GND
35	SMCSADR2	75	HDATA24	115	VCC	155	VCC	195	VCC
36	SMCSADR3	76	HDATA25	116	GND	156	GND	196	GND
37	SMCSID0	77	HDATA26	117	CMADR12	157	CMDATA24		
38	SMCSID1	78	VCC	118	CMADR13	158	CMDATA25		
39	SMCSID2	79	GND	119	CMADR14	159	CMDATA26		
40	SMCSID3	80	HDATA27	120	CMADR15	160	VCC		

FIGURE 2. Terminal connections.

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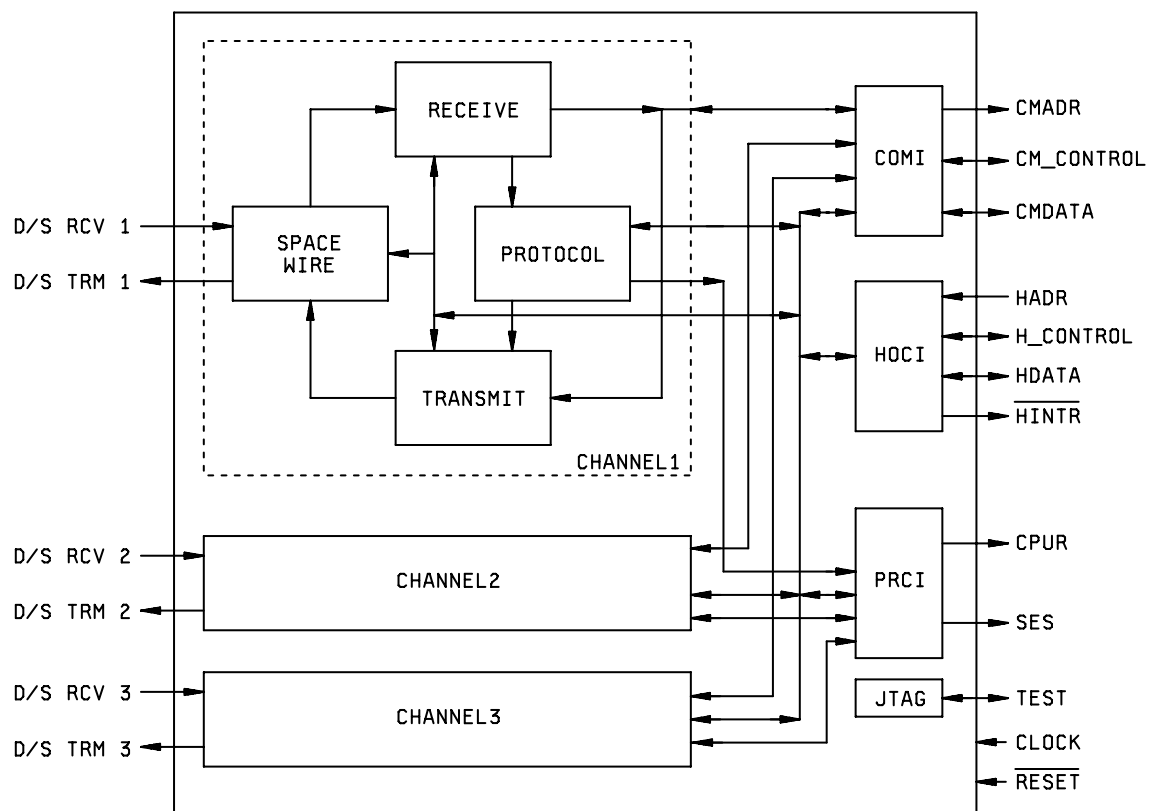


FIGURE 3. Block diagram.

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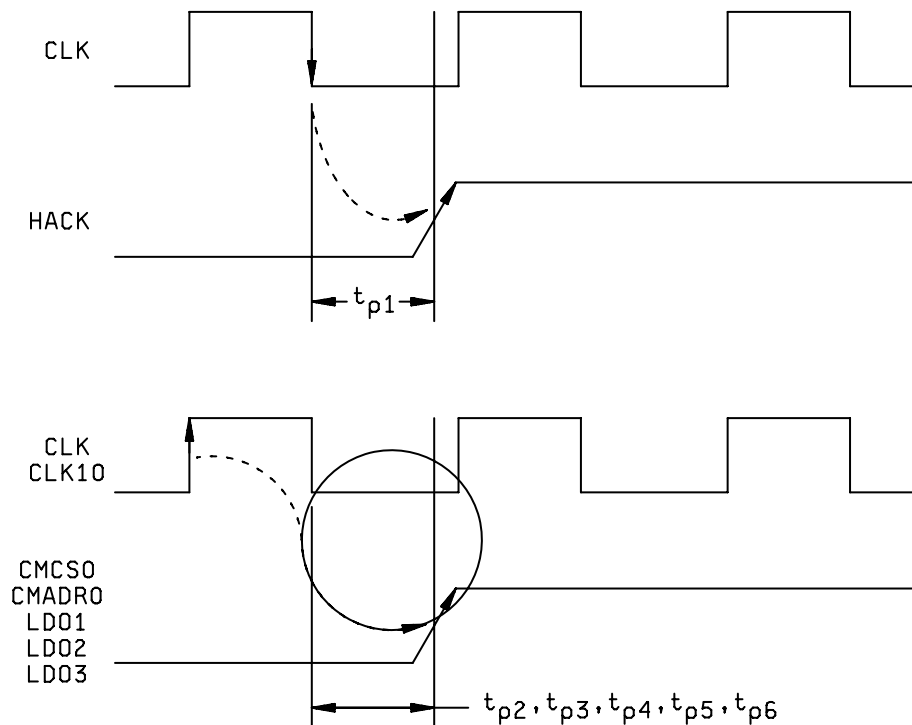


FIGURE 4. Timing waveforms.

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4. VERIFICATION

4.1 Sampling and inspection. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. For device class M, sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.

4.2 Screening. For device classes Q and V, screening shall be in accordance with MIL-PRF-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection.

4.2.1 Additional criteria for device class M.

a. Burn-in test, method 1015 of MIL-STD-883.

(1) Test condition A, B, C, D or E. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015.

(2) $T_A = +125^{\circ}\text{C}$, minimum.

b. Interim and final electrical test parameters shall be as specified in table II herein.

4.2.2 Additional criteria for device classes Q and V.

a. The burn-in test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.

b. Interim and final electrical test parameters shall be as specified in table II herein.

c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in MIL-PRF-38535, appendix B.

4.3 Qualification inspection for device classes Q and V. Qualification inspection for device classes Q and V shall be in accordance with MIL-PRF-38535. Inspections to be performed shall be those specified in MIL-PRF-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

4.4 Conformance inspection. Technology conformance inspection for classes Q and V shall be in accordance with MIL-PRF-38535 including groups A, B, C, D, and E inspections and as specified herein. Quality conformance inspection for device class M shall be in accordance with MIL-PRF-38535, appendix A and as specified herein. Inspections to be performed for device class M shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

4.4.1 Group A inspection.

a. Tests shall be as specified in table II herein.

b. For device class M, subgroups 7 and 8 tests shall be sufficient to verify the truth table. For device classes Q and V, subgroups 7 and 8 shall include verifying the functionality of the device.

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TABLE IIA. Electrical test requirements.

Test requirements	Subgroups (in accordance with MIL-STD-883, method 5005, table I)	Subgroups (in accordance with MIL-PRF-38535, table III)	
	Device class M	Device class Q	Device class V
Interim electrical parameters (see 4.2)	1,7,9	1,7,9	1,7,9
Final electrical parameters (see 4.2)	1, 2, 3, 4, 7, 8, 9, 10, 11 <u>1/</u>	1, 2, 3, 4, 7, 8, 9, 10, 11 <u>1/</u>	1, 2, 3, 4, 7, 8, 9, 10, 11, <u>2/ 3/</u>
Group A test requirements (see 4.4)	1, 2, 3, 4, 7, 8, 9, 10, 11	1, 2, 3, 4, 7, 8, 9, 10, 11	1, 2, 3, 4, 7, 8, 9, 10, 11
Group C end-point electrical parameters (see 4.4)	1,7,9	1,7,9	1,7,9 <u>3/</u>
Group D end-point electrical parameters (see 4.4)	1,7,9	1,7,9	1,7,9
Group E end-point electrical parameters (see 4.4)	1,7,9	1,7,9	1,7,9

1/ PDA applies to subgroup 1.

2/ PDA applies to subgroups 1 and 7.

3/ Delta limits, as specified in table IIB, shall be required where specified, and the delta values shall be completed with reference to the zero hour electrical parameters.

TABLE IIB. Burn-in delta parameters (25°C).

Parameter	Limit	Unit
IIL/IIH	+/- 10% of specified value in table 1	μA
IOZL/IOZH	+/- 10% of specified value in table 1	μA
ICCSB	+/- 10% of specified value in table 1	mA

Note: The parameters shall be recorded before and after the required burn-in and life test to determine the delta limits.

4.4.2 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table IIA herein.

4.4.2.1 Additional criteria for device class M. Steady-state life test conditions, method 1005 of MIL-STD-883:

- Test condition or . The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.
- $T_A = +125^\circ\text{C}$, minimum.
- Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

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4.4.2.2 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.

4.4.3 Group D inspection. The group D inspection end-point electrical parameters shall be as specified in table II herein.

4.4.4 Group E inspection. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein).

- a. End-point electrical parameters shall be as specified in table II herein.
- b. For device classes Q and V, the devices or test vehicle shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535 for the RHA level being tested. For device class M, the devices shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535, appendix A for the RHA level being tested. All device classes must meet the postirradiation end-point electrical parameter limits as defined in table I at $T_A = +25^{\circ}\text{C} \pm 5^{\circ}\text{C}$, after exposure, to the subgroups specified in table II herein.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.1.1 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor prepared specification or drawing.

6.1.2 Substitutability. Device class Q devices will replace device class M devices.

6.2 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.

6.3 Record of users. Military and industrial users should inform Defense Supply Center Columbus (DSCC) when a system application requires configuration control and which SMD's are applicable to that system. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-0544.

6.4 Comments. Comments on this drawing should be directed to DSCC-VA, Columbus, Ohio 43216-5000, or telephone (614) 692-0547.

6.5 Abbreviations, symbols, and definitions. The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535 and MIL-HDBK-1331.

6.6 Sources of supply.

6.6.1 Sources of supply for device classes Q and V. Sources of supply for device classes Q and V are listed in QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DSCC-VA and have agreed to this drawing.

6.6.2 Approved sources of supply for device class M. Approved sources of supply for class M are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DSCC-VA.

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STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 08-01-09

Approved sources of supply for SMD 5962-08A01 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This information bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535.

Standard microcircuit drawing PIN <u>1/</u>	Vendor CAGE number	Vendor similar PIN <u>2/</u>
5962-08A01QXC	F7400	AT7911EFA-MQ
5962-08A01VXC	F7400	AT7911EFA-SV

- 1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availability.
- 2/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE
number

Vendor name
and address

F7400

ATMEL Nantes SA
BP 70602
44306 Nantes Cedex 3, France

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in the information bulletin.